

Vishay Semiconductors

HALOGEN

FREE

Ultrafast Rectifier, 10 A FRED Pt®



| PRIMARY CHARACTERISTICS | | | | | | | | |
|----------------------------------|--------------------|--|--|--|--|--|--|--|
| I _{F(AV)} | 2 x 5 A | | | | | | | |
| V _R | 200 V | | | | | | | |
| V _F at I _F | 0.87 V | | | | | | | |
| t _{rr} typ. | See Recovery table | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Package | TO-220AB 3L | | | | | | | |
| Circuit configuration | Common cathode | | | | | | | |

FEATURES

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | | |
|-------------------------------------|--------------|-----------------------------------|--|-------------|-------|--|--|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | | | |
| Peak repetitive reverse voltage | | V_{RRM} | | 200 | V | | | | | |
| A | per leg | ı | | 5 | | | | | | |
| Average rectified forward current | total device | I _{F(AV)} | Rated V _R , T _C = 149 °C | 10 | | | | | | |
| Non-repetitive peak surge current p | er leg | I _{FSM} | | 50 | Α | | | | | |
| Peak repetitive forward current per | leg | I _{FM} | Rated V_R , square wave, 20 kHz $T_C = 149 ^{\circ}C$ | 10 | | | | | | |
| Operating junction and storage tem | peratures | T _J , T _{Stg} | | -65 to +175 | °C | | | | | |

| ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified) | | | | | | | | | | |
|--|-------------------------------------|--|------|------|------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 200 | - | - | | | | | |
| Forward voltage | V _F | I _F = 5 A, T _J = 125 °C | - | 0.87 | 0.99 | V | | | | |
| | | I _F = 10 A, T _J = 125 °C | - | 1.02 | 1.20 | | | | | |
| | | I _F = 10 A | - | 1.12 | 1.25 | | | | | |
| Poverse leekage ourrent | | $V_R = V_R$ rated | - | - | 10 | | | | | |
| Reverse leakage current | I _R | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | - | 250 | μA | | | | |
| Junction capacitance C _T V _R = 200 V | | - | 8 | - | pF | | | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | | | |



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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|---|------------------|----------------------------------|---|------|------|-------|---------|--|--|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | | | |
| Reverse recovery time | | $I_F = 1.0 \text{ A}, dI_F/dt =$ | $I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | | 35 | | | |
| | t _{rr} | $I_F = 0.5 \text{ A}, I_R = 1.0$ | - | - | 25 | | | | |
| | | T _J = 25 °C | | - | 24 | - | ns A nC | | |
| | | T _J = 125 °C | | - | 35 | - | | | |
| Peak recovery current | I _{RRM} | T _J = 25 °C | I _F = 5 A dI _F /dt = 200 A/μs | - | 3.3 | - | | | |
| | | T _J = 125 °C | V _R = 160 V | - | 5.0 | - | | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 33 | - | | | |
| | Q_{rr} | T _J = 125 °C | | - | 76 | - | | | |

| THERMAL MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|-----------------------------------|---|--------------|------|------------|------------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | |
| Thermal resistance, junction to case per leg | R _{thJC} | | - | - | 5 | | | | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | | - | - | 50 | °C/W | | | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth, and greased | - | 0.5 | - | | | | |
| Weight | | | - | 2.0 | - | g | | | |
| vveignt | | | - | 0.07 | - | OZ. | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | |
| Marking device | | Case style TO-220AB 3L | MUR1020CT | | | | | | |

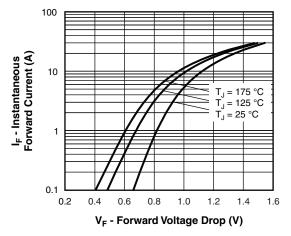


Fig. 1 - Typical Forward Voltage Drop Characteristics

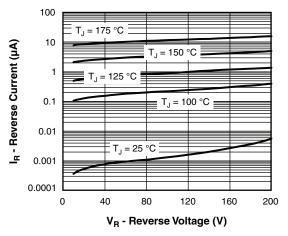


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



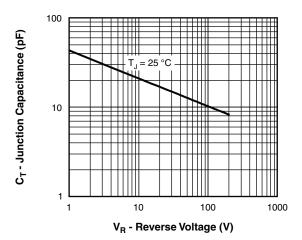


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

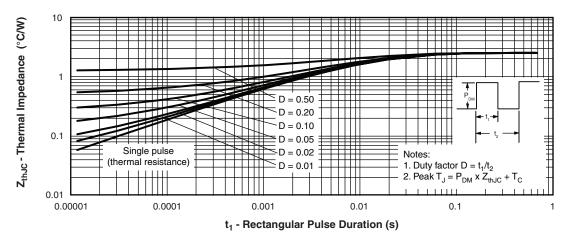


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

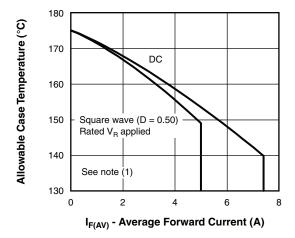


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

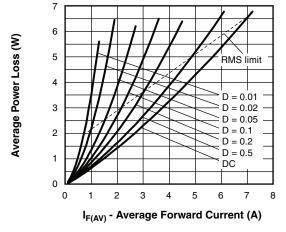


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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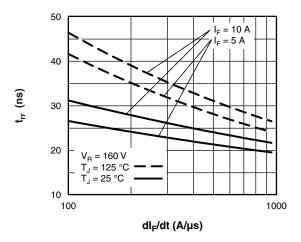


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

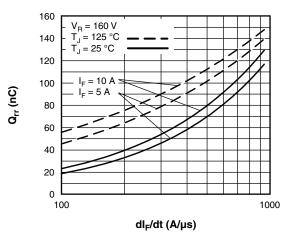
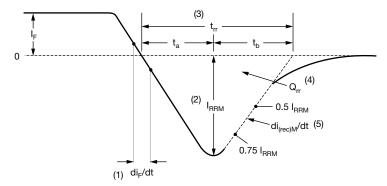


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{F}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

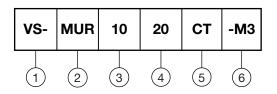
Fig. 9 - Reverse Recovery Waveform and Definitions



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Ultrafast MUR series

3 - Current rating (10 = 10 A)

Voltage rating (20 = 200 V)

5 - CT = center tap (dual) 3L TO-220AB, D²PAK (TO-263AB), TO-262AA

6 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | | | |
|---|----|--------------------------|--|--|--|--|--|--|--|
| PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION | | | | | | | | | |
| VS-MUR1020CT-M3 | 50 | Antistatic plastic tubes | | | | | | | |

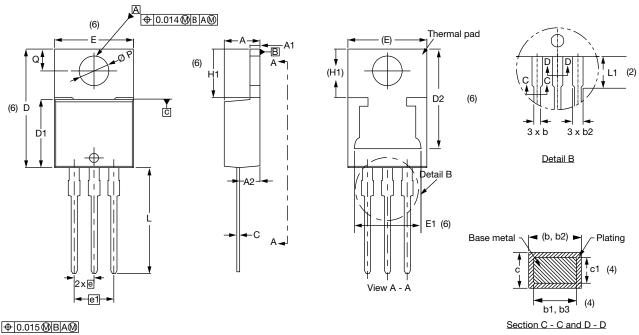
| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--------------------------|
| Dimensions | www.vishay.com/doc?96154 |
| Part marking information | www.vishay.com/doc?95028 |

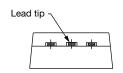


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TO-220AB 3L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES | |
|--------|-------------|-------|--------|-------|-------|--------|-------------|-------|--------|-------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | NOTES | STIVIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | | | D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | | Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | | е | 2.41 | 2.67 | 0.095 | 0.105 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | | H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | | ØΡ | 3.54 | 3.91 | 0.139 | 0.154 | |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 | | Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | | | | | | | |

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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